





Plating Process

Plating Equipment for Semiconductor Panel Level Packaging

Technical Specifications

Plating Equipment

Panel Size (mm)

300/500/600/700

Anode

Insoluble/ Multiple Zone

Convection/Agitation

Paddle Type & Fan Type

Membrance

Ionic Exchange Membrance

Warpage allowance

Max. ≤10 mm

Cathode Contact Failure Detection

Yes

Blanket uniformity

> 95%

Application

RDL Trace & Via Filling Copper Bump & Pillar Plating Stud & Heat Sink Plating

Type of carrier substrate

Stainless, Epoxy, Glass & CCL (FR-4)

Description

Process flow

Loading→Micro Etch→Acid Rinse→Cu Plating→Water Rinse→Dry→Unloading

*Specific performance parameters depend on the application.







→ Features

- Hassle-Free Operation
 Jig-free design for easy handling, less maintenance, and maximum uptime.
- Scalable & Flexible
 Modular design expands with your needs and simplifies maintenance.
- Superior Plating Quality
 Multi-anode system delivers >95% uniformity and minimizes edge effects.
- High-Performance Capability
 Achieves copper thickness beyond
 150 μm with >15 ASD for advanced applications.
- Smart CMS Integration
 Inline chemical monitoring with automatic dosing for stable process control.

